

CY2314ANZ

14 Output, 3.3V SDRAM Buffer for Desktop PCs with 3 DIMMs

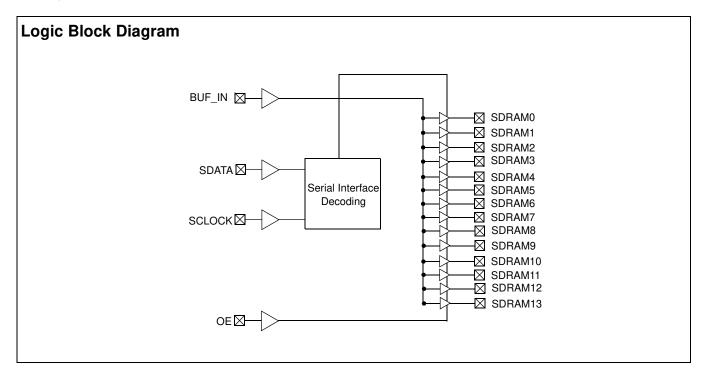
Features

- One input to 14 output buffer or driver
- Supports up to three SDRAM DIMMs
- Two additional outputs for feedback
- Serial interface for output control
- Low skew outputs
- Up to 100 MHz operation
- Multiple V_{DD} and V_{SS} pins for noise reduction
- Dedicated OE pin for testing
- Low EMI outputs
- 28-pin SOIC (300-mil) package
- 3.3V operation

Functional Description

The CY2314ANZ is a 3.3V buffer designed to distribute high speed clocks in desktop PC applications. The part has 14 outputs, 12 of which can be used to drive up to three SDRAM DIMMs. The remaining can be used for external feedback to a PLL. The device operates at 3.3V and outputs can run up to 100 MHz.

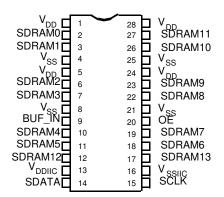
The CY2314ANZ also includes a serial interface which can enable or disable each output clock. On power up, all output clocks are enabled. A separate Output Enable pin facilitates testing on ATE.





Pin Configuration

Figure 1. 28-Pin SOIC Top View



Device Functionality

OE	SDRAM [0-13]
0	High-Z
1	1 x BUF_IN

Serial Configuration Map

■ The serial bits are read by the clock driver in the following order:

Byte 0 - Bits 7, 6, 5, 4, 3, 2, 1, 0

Byte 1 - Bits 7, 6, 5, 4, 3, 2, 1, 0

Byte N - Bits 7, 6, 5, 4, 3, 2, 1, 0

- Reserved and unused bits should be programmed to "0"
- Serial interface address for the CY2314ANZ is:

A6	A5	A 4	A3	A2	A1	A 0	R/W
1	1	0	1	0	0	1	

Table 1. Byte 0: SDRAM Active/Inactive Register(1 = Enable, 0 = Disable), Default = Enabled

Bit	Pin #	Description		
Bit 7	11	SDRAM5 (Active/Inactive)		
Bit 6	10	SDRAM4 (Active/Inactive)		
Bit 5		Reserved, Drive to 0		
Bit 4		Reserved, Drive to 0		
Bit 3	7	SDRAM3 (Active/Inactive)		
Bit 2	6	SDRAM2 (Active/Inactive)		
Bit 1	3	SDRAM1 (Active/Inactive)		
Bit 0	2	SDRAM0 (Active/Inactive)		

Table 2. Byte 1: SDRAM Active/Inactive Register (1 = Active, 0 = Inactive), Default = Active

Bit	Pin #	Description
Bit 7	27	SDRAM11 (Active/Inactive)
Bit 6	26	SDRAM10 (Active/Inactive)
Bit 5	23	SDRAM9 (Active/Inactive)
Bit 4	22	SDRAM8 (Active/Inactive)
Bit 3		Reserved, Drive to 0
Bit 2		Reserved, Drive to 0
Bit 1	19	SDRAM7 (Active/Inactive)
Bit 0	18	SDRAM6 (Active/Inactive)

Table 3. Byte 2: SDRAM Active/Inactive Register(1 = Active, 0 = Inactive), Default = Active

Bit	Pin #	Description	
Bit 7	17	SDRAM13 (Active/Inactive)	
Bit 6	12	SDRAM12 (Active/Inactive)	
Bit 5		Reserved, Drive to 0	
Bit 4		Reserved, Drive to 0	
Bit 3		Reserved, Drive to 0	
Bit 2		Reserved, Drive to 0	
Bit 1		Reserved, Drive to 0	
Bit 0		Reserved, Drive to 0	



Maximum Ratings

Supply Voltage to Ground Potential0.5V to +7.0V
DC Input Voltage (Except BUF_IN) –0.5V to V _{DD} + 0.5V
DC Input Voltage (BUF_IN)0.5V to +7.0V

Storage Temperature65°C to) +150°C
Junction Temperature	150°C
Static Discharge Voltage	00001
(per MIL-STD-883, Method 3015)	.>2000V

Operating Conditions^[1]

Parameter	Description	Min	Max	Unit
V _{DD}	Supply Voltage	3.135	3.465	V
T _A	Operating Temperature (Ambient Temperature)	0	70	°C
CL	Load Capacitance		30	pF
C _{IN}	Input Capacitance		7	pF
t _{PU}	Power up time for all VDDs to reach minimum specified voltage (power ramps must be monotonic)	0.05	50	ms

Electrical Characteristics Over the Operating Range

Parameter	Description	Test Conditions	Min	Мах	Unit
V _{IL}	Input LOW Voltage ^[2]	Except serial interface pins		0.8	V
V _{ILiic}	Input LOW Voltage	For serial interface pins only		0.7	V
V _{IH}	Input HIGH Voltage ^[2]		2.0		V
I _{IL}	Input LOW Current (BUF_IN input)	V _{IN} = 0V	-10	10	μΑ
I _{IL}	Input LOW Current (Except BUF_IN Pin)	V _{IN} = 0V		100	μΑ
I _{IH}	Input HIGH Current	$V_{IN} = V_{DD}$	-10	10	μA
V _{OL}	Output LOW Voltage ^[3]	I _{OL} = 25 mA		0.4	V
V _{OH}	Output HIGH Voltage ^[3]	I _{OH} = -36 mA	2.4		V
I _{DD}	Supply Current ^[3]	Unloaded outputs, 100 MHz		200	mA
I _{DD}	Supply Current ^[3]	Loaded outputs, 100 MHz		290	mA
I _{DD}	Supply Current ^[3]	Unloaded outputs, 66.67 MHz		150	mA
I _{DD}	Supply Current ^[3]	Loaded outputs, 66.67 MHz		185	mA
I _{DDS}	Supply Current	BUF_IN=V _{DD} or V _{SS} All other inputs at V _{DD}		500	μΑ

Notes

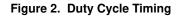
- Electrical parameters are guaranteed under the operating conditions specified.
 BUF_IN input has a threshold voltage of V_{DD}/2.
 Parameter is guaranteed by design and characterization. Not 100% tested in production.



Switching Characteristics^[4] Over the Operating Range

Parameter	Name	Test Conditions	Min	Тур	Max	Unit
	Maximum Operating Frequency				100	MHz
	Duty Cycle ^[3, 5] = $t_2 \div t_1$	Measured at 1.5V	45.0	50.0	55.0	%
t ₃	Rising Edge Rate ^[3]	Measured between 0.4V and 2.4V	0.9	1.5	4.0	V/ns
t ₄	Falling Edge Rate ^[3]	Measured between 2.4V and 0.4V	0.9	1.5	4.0	V/ns
t ₅	Output to Output Skew ^[3]	All outputs equally loaded	-250		+250	ps
t ₆	SDRAM Buffer LH Propogation Delay ^[3]	Input edge greater than 1 V/ns	1.0	3.5	5.0	ns
t ₇	SDRAM Buffer HL Propogation Delay ^[3]	Input edge greater than 1 V/ns	1.0	3.5	5.0	ns
t ₈	SDRAM Buffer Enable Delay ^[3]	Input edge greater than 1 V/ns	1.0	5	12	ns
t ₉	SDRAM Buffer Disable Delay ^[3]	Input edge greater than 1 V/ns	1.0	20	30	ns

Switching Waveforms



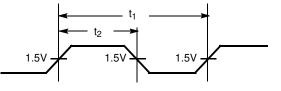


Figure 3. All Outputs Rise/Fall Time

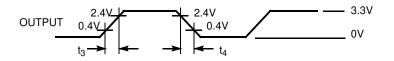
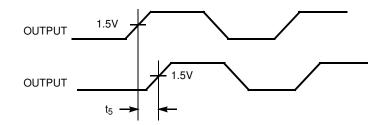


Figure 4. Output-Output Skew



Notes

All parameters specified with loaded outputs.
 Duty cycle of input clock is 50%. Rising and falling edge rate of the input clock is greater than 1 V/ns.



Switching Waveforms (continued)

Figure 5. SDRAM Buffer LH and HL Propagataion Delay

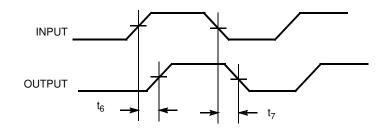
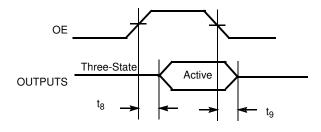
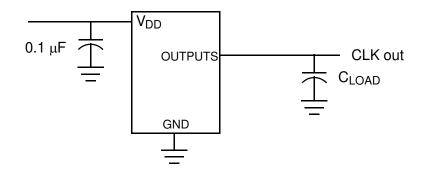


Figure 6. SDRAM Buffer Enable and Disable Times



Test Circuit





Application Information

Clock traces must be terminated with either series or parallel termination, as is normally done.

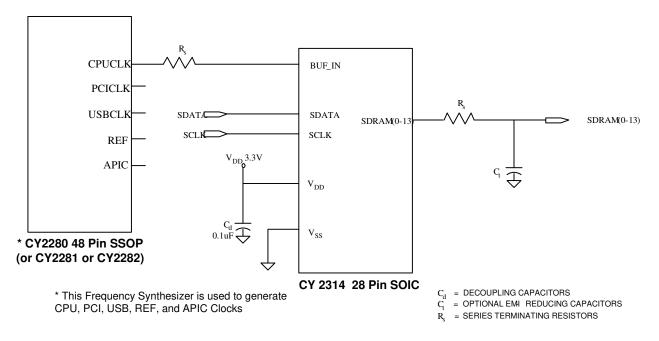


Figure 7. Application Circuit

Recommendation

- Surface mount, low ESR,and ceramic capacitors must be used for filtering. Typically, these capacitors have a value of 0.1 μF. In some cases, smaller value capacitors may be required.
- The value of the series terminating resistor satisfies the following equation, where Rtrace is the loaded characteristic impedance of the trace, Rout is the output impedance of the buffer (typically 25Ω), and Rseries is the series terminating resistor. Rseries > Rtrace – Rout
- Footprints must be laid out for optional EMI reducing capacitors, which should be placed as close to the terminating resistor as is physically possible. Typical values of these capacitors range from 4.7 pF to 22 pF.
- A ferrite bead may be used to isolate the board V_{DD} from the clock generator V_{DD} island. Ensure that the ferrite bead offers greater than 50Ω impedance at the clock frequency, under loaded DC conditions. Refer to the application note Layout and Termination Techniques for Cypress Clock Generators for more details.
- If a ferrite bead is used, a 10 μF to 22 μF tantalum bypass capacitor should be placed close to the ferrite bead. This capacitor prevents power supply droop during current surges.

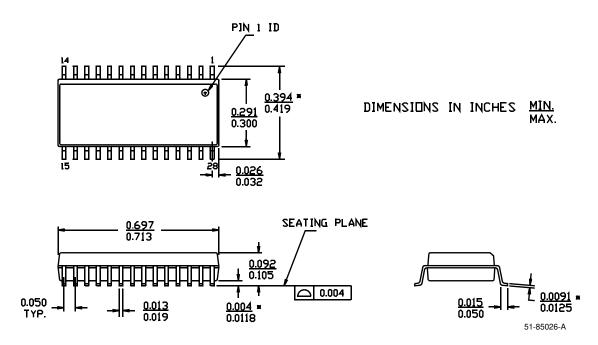
Ordering Information

Ordering Code	Package Name	Package Type	Operating Range
Pb-Free			
CY2314ANZSXC-1	SZ283	28-Pin SOIC	Commercial
CY2314ANZSXC-1T	SZ283	28-Pin SOIC - Tape and Reel	Commercial



Package Diagram

Figure 8. 28-Pin (300-Mil) Molded SOIC SZ283





Document History Page

Document Document	Document Title: CY2314ANZ 14 Output, 3.3V SDRAM Buffer for Desktop PCs with 3 DIMMs Document Number: 38-07143					
Rev.	ECN No.	Orig. of Change	Submission Date	Description of Change		
**	110252	DSG	11/18/01	Change from Spec number: 38-00687 to 38-07143		
*A	121830	RBI	12/14/02	Power up requirements added to Operating Conditions Information		
*B	2606695	KVM/PYRS	11/13/08	Update Ordering Information Table: Remove CY2314ANZSC-1 Add Pb-free devices CY2314ANZSXC-1 and CY2314ANZSXC-1T		

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